



100V PNP MEDIUM POWER TRANSISTOR IN TO252

Features

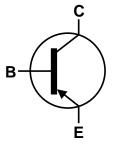
- BV_{CEO} > -100V
- I_C = -3A High Continuous Collector Current
- I_{CM} = -5A Peak Pulse Current
- Ideal for Power Switching or Amplification Applications
- Complementary NPN Type: MJD31CUQ
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The MJD32CUQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

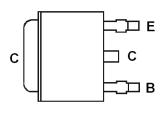
Mechanical Data

- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.34 grams (Approximate)





Device Schematic



Pinout Configuration Top View

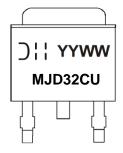
Ordering Information (Note 4)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
			Reel Size (Iliches)	rape widin (ililii)	Qty.	Carrier
MJD32CUQ-13	TO252 (DPAK)	MJD32CU	13	16	2,500	Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information





Absolute Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vcво	-120	V
Collector-Emitter Voltage	Vceo	-100	V
Emitter-Base Voltage	VEBO	-7	V
Continuous Collector Current	Ic	-3	A
Peak Pulse Collector Current	Ісм	-5	A
Continuous Base Current	lв	-1	А
Power Dissipation	P _D	16	W

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		2.60		
Power Dissipation	(Note 6)	PD	2.30	W	
	(Note 7)		1.45]	
	(Note 5)		48		
Thermal Resistance, Junction to Ambient Air	(Note 6)	R _θ ЈА	54		
	(Note 7)		86	°C/W	
Thermal Resistance, Junction to Leads (Note 8)		R _{0JL}	7.8		
Thermal Resistance, Junction to Case (Note 7)		Rejc	7.3		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 9)

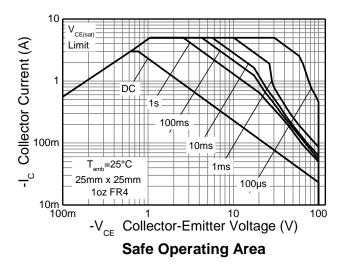
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

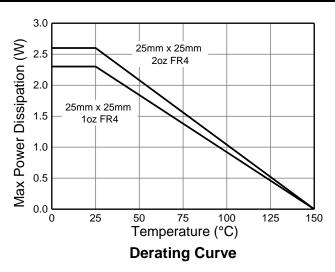
Notes:

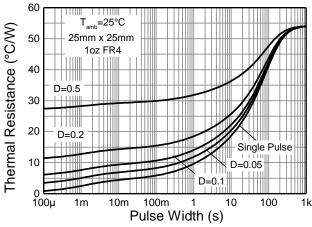
- 5. For a device mounted with the exposed collector pad on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady state.
- 6. Same as note (5), except mounted on 25mm x 25mm 1oz copper.
- 7. Same as note (5), except mounted on minimum recommended pad (MRP) layout.
- 8. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

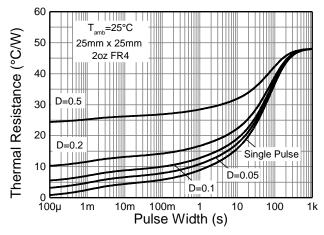


Thermal Characteristics



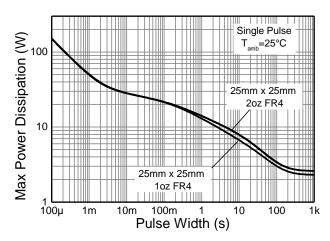






Transient Thermal Impedance

Transient Thermal Impedance



Pulse Power Dissipation



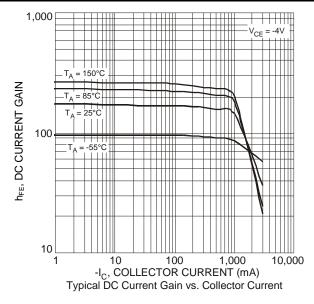
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

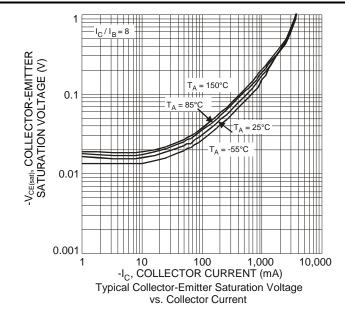
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	-120	-	_	V	Ic = -20μA
Collector-Emitter Breakdown Voltage (Note 10)	BVceo	-100	-	_	V	Ic = -30mA
Emitter-Base Breakdown Voltage	BVEBO	-7	-	_	V	I _E = -100μA
Collector-Base Cut-off Current	Ісво	-	-	-1	μΑ	V _{CB} = -100V
Collector Cut-off Current	I _{CEO}	-	-	-1	μΑ	$V_{CE} = -60V$
Collector Cut-off Current	ICES	-	-	-1	μΑ	Vce = -100V
Emitter Cut-off Current	I _{EBO}	_	-	-1	μΑ	V _{EB} = -5V
		_	-	-300	mV	$I_C = -1A$, $I_B = -100mA$
Collector-Emitter Saturation Voltage (Note 10)	VCE(sat)	-	-	-500	mV	Ic = -2A, I _B = -200mA
		_	-	-700	mV	Ic = -3A, I _B = -375mA
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	-	-	-1.2	V	Ic = -2A, I _B = -200mA
Base-Emitter Turn-On Voltage (Note 10)	\/	-	-	-950	mV	Ic = -1A, VcE = -2V
Base-Emilier Fum-On Vollage (Note 10)	V _{BE(on)}	_	-	-1.4	V	Ic = -3A, VcE = -4V
DC Current Gain (Note 10)	hFE	25		_		Vce = -4V, Ic = -1A
DC Current Gain (Note 10)		10	_	50	_	$V_{CE} = -4V$, $I_{C} = -3A$
Current Signal Current Gain	hfE	20	-	_	-	$V_{CE} = -10V$, $I_{C} = -0.5A$, $f = 1kHz$
Current Gain-Bandwidth Product	f⊤	3.0		_	MHz	Ic = -0.5A, VcE = -10V, f = 1MHz

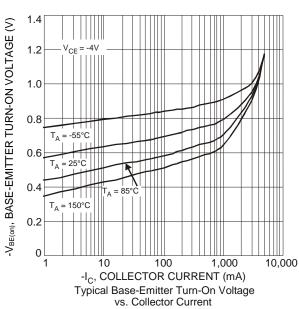
Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

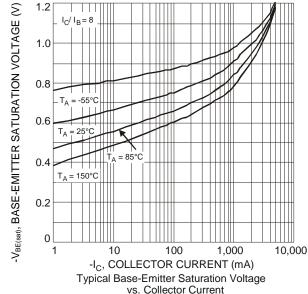


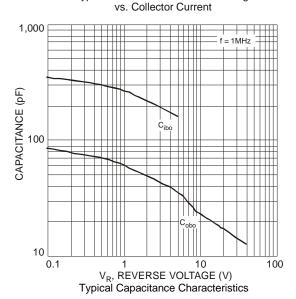
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









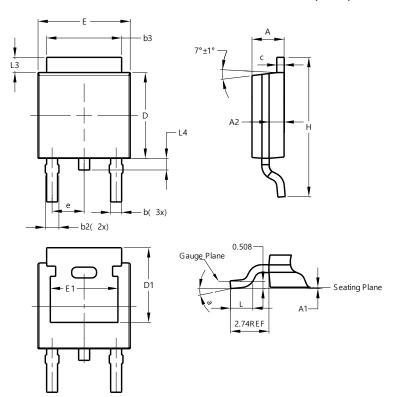




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)

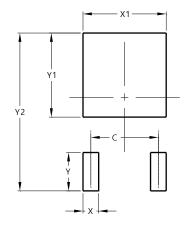


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.50	5.33		
O	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21		-		
е	2.286 BSC				
Е	6.45	6.70	6.58		
E1	4.32				
I	9.40	10.41	9.91		
Г	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Υ	2.600
Y1	5.700
Y2	10.700



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